



MPC817X1 Series

DIP4, DC Input, Photo Transistor Coupler

Description

The MPC817X1 series combine an AlGaAs infrared emitting diode as the emitter which is optically coupled to a silicon planar phototransistor detector in a plastic DIP4 package with different lead forming options. With the robust coplanar double mold structure, MPC817X1 series provide the most stable isolation feature.

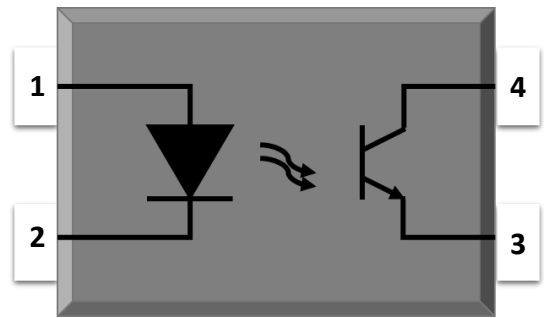
Features

- High isolation 5000 VRMS
- CTR flexibility available see order information
- DC input with transistor output
- Operating temperature range - 55 °C to 110 °C
- RoHS & REACH Compliance
- MSL class 1
- Halogen free (Optional)
- Regulatory Approvals
 - UL - UL1577
 - VDE - EN60747-5-5(VDE0884-5)
 - CQC – GB4943.1, GB8898

Applications

- Switch mode power supplies
- Programmable controllers
- Household appliances
- Office equipment

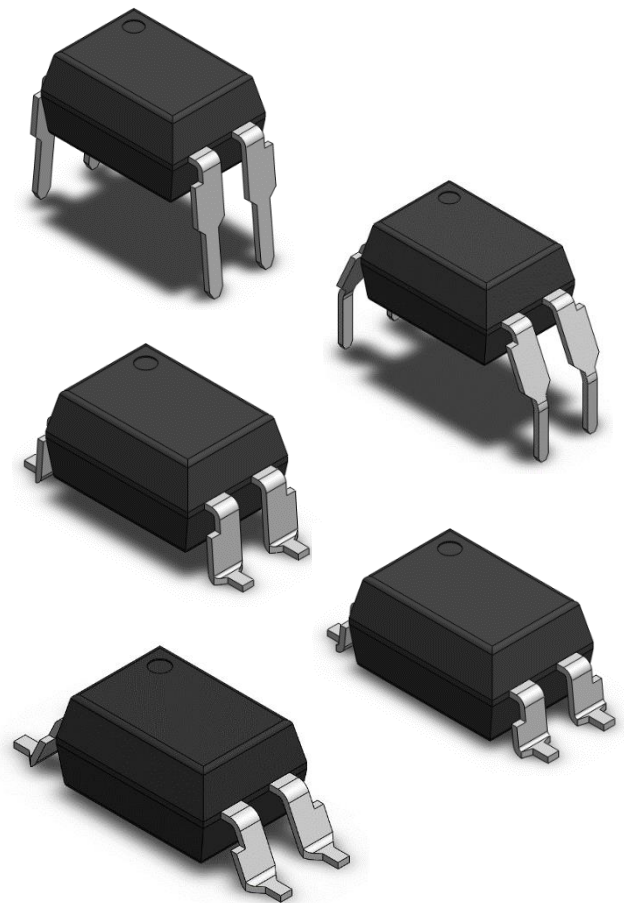
SCHEMATIC



PIN DEFINITION

1. Anode
2. Cathode
3. Emitter
4. Collector

PACKAGE OUTLINE





MPC817X1 Series

DIP4, DC Input, Photo Transistor Coupler

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT	NOTE
INPUT				
Forward Current	I_F	60	mA	
Peak Forward Current	I_{FP}	1	A	1
Reverse Voltage	V_R	6	V	
Input Power Dissipation	P_I	100	mW	
OUTPUT				
Collector - Emitter Voltage	V_{CEO}	35	V	
Emitter - Collector Voltage	V_{ECO}	7	V	
Collector Current	I_C	50	mA	
Output Power Dissipation	P_O	150	mW	
COMMON				
Total Power Dissipation	P_{tot}	200	mW	
Isolation Voltage	V_{iso}	5000	Vrms	2
Operating Temperature	T_{opr}	-55~110	°C	
Storage Temperature	T_{stg}	-55~125	°C	
Soldering Temperature	T_{sol}	260	°C	

Note 1. 100 μ s pulse, 100Hz frequency

Note 2. AC For 1 Minute, R.H. = 40 ~ 60%



MPC817X1 Series

DIP4, DC Input, Photo Transistor Coupler

ELECTRICAL OPTICAL CHARACTERISTICS at Ta=25°C								
PARAMETER	SYMBOL	MIN	TYP.	MAX.	UNIT	TEST CONDITION	NOTE	
INPUT								
Forward Voltage	V _F	-	1.24	1.4	V	IF=10mA		
Reverse Current	I _R	-	-	10	μA	VR=6V		
Input Capacitance	C _{in}	-	10	-	pF	V=0, f=1kHz		
OUTPUT								
Collector Dark Current	I _{CEO}	-	-	100	nA	VCE=20V, IF=0		
Collector-Emitter Breakdown Voltage	BV _{CEO}	35	-	-	V	IC=0.1mA, IF=0		
Emitter-Collector Breakdown Voltage	BV _{ECO}	6	-	-	V	IE=0.1mA, IF=0		
TRANSFER CHARACTERISTICS								
Current Transfer Ratio	MPC817A1	CTR	80	-	160	%	IF=5mA, VCE=5V	
	MPC817B9		130	-	260			
	MPC817C1		200	-	400			
	MPC817D1		300	-	600			
Collector-Emitter Saturation Voltage	V _{CE(sat)}	-	0.06	0.2	V	IF=20mA, IC=1mA		
Isolation Resistance	R _{iso}	10 ¹²	10 ¹⁴	-	Ω	DC500V, 40 ~ 60% R.H.		
Floating Capacitance	C _{io}	-	0.4	1	pF	V=0, f=1MHz		
Cut-off Frequency	f _c	-	80	-	kHz	VCE=2V, IC=2mA RL=100Ω, -3dB	3	
Response Time (Rise)	t _r	-	6	18	μs	VCE=2V, IC=2mA	4	
Response Time (Fall)	t _f	-	8	18	μs	RL=100Ω	4	

Note 3. Fig.12&13

Note 4. Fig.14



CHARACTERISTIC CURVES

Fig.1 Forward Current vs. Ambient Temperature

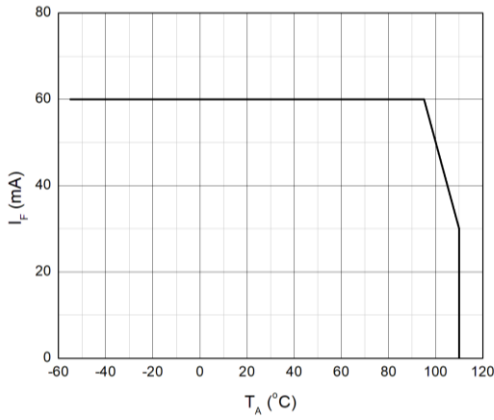


Fig.2 Collector Power Dissipation vs. Ambient Temperature

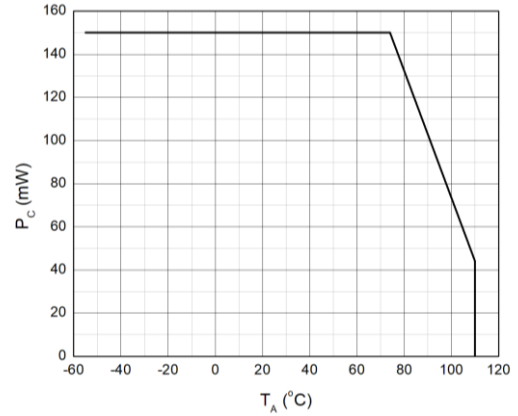


Fig.3 Forward Current vs. Forward Voltage

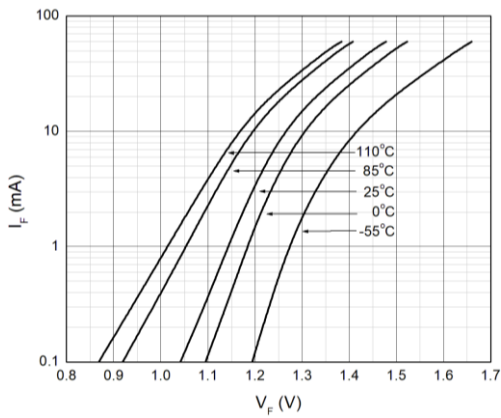


Fig.4 Collector Dark Current vs. Ambient Temperature

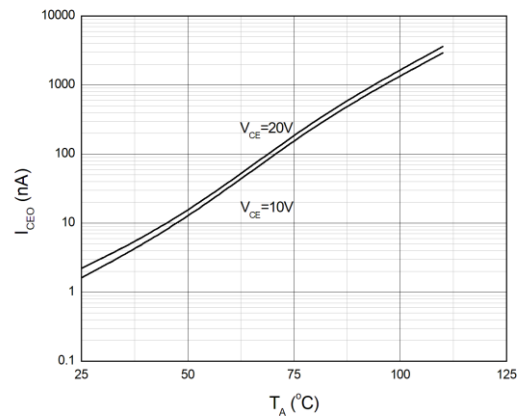


Fig.5 Collector Current vs. Collector-emitter Voltage

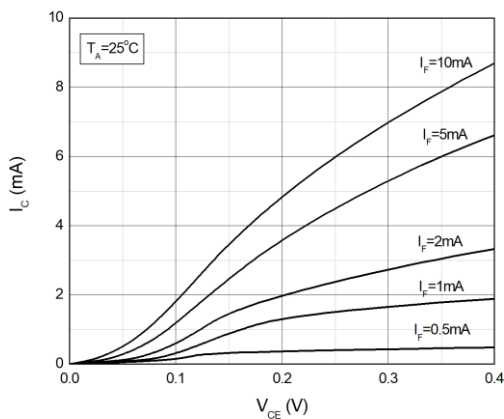
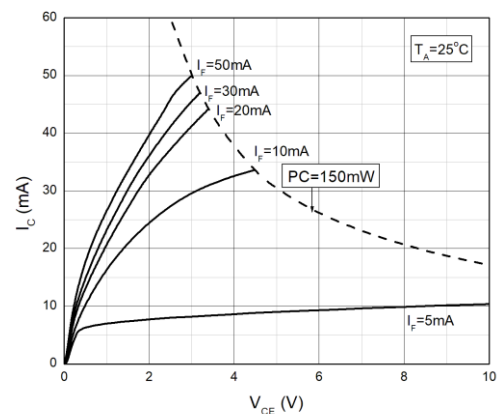


Fig.6 Collector Current vs. Collector-emitter Voltage





CHARACTERISTIC CURVES

Fig.7 Normalized Current Transfer Ratio vs. Forward Current

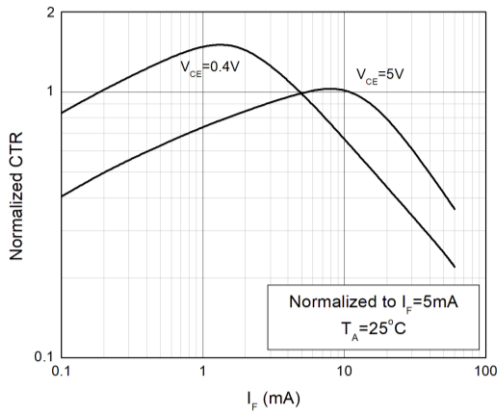


Fig.8 Normalized Current Transfer Ratio vs. Ambient Temperature

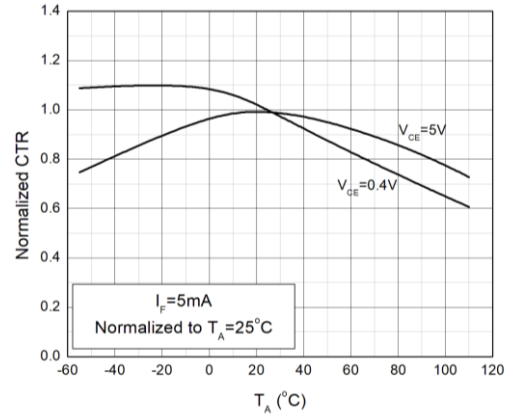


Fig.9 Collector-emitter Saturation Voltage vs. Ambient Temperature

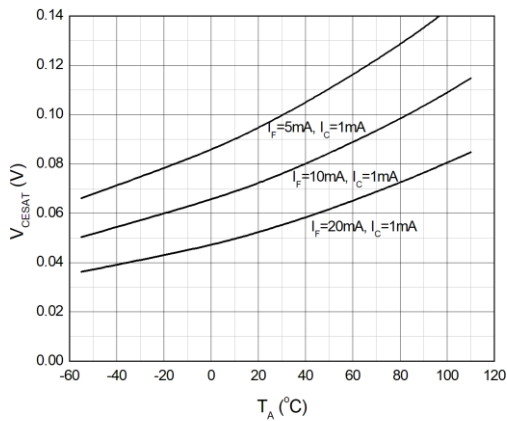


Fig.10 Switching Time vs. Load Resistance

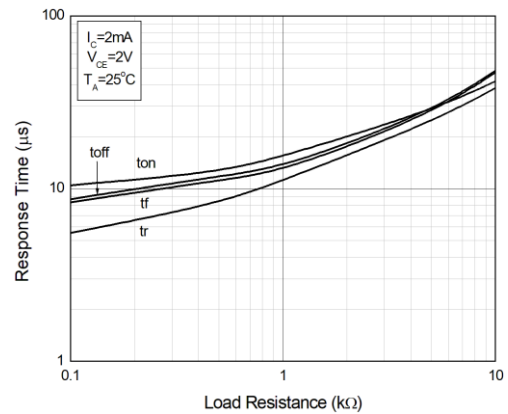
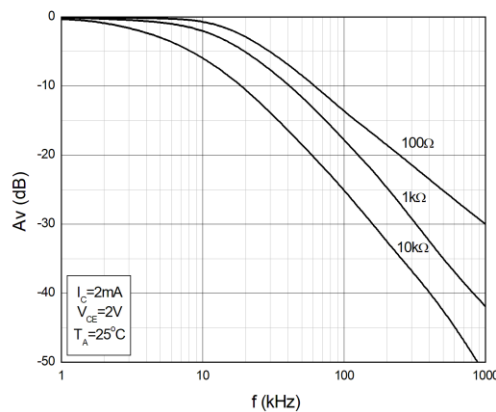


Fig.11 Frequency Response



TEST CIRCUITS

Fig.12 Test Circuits of Response Time

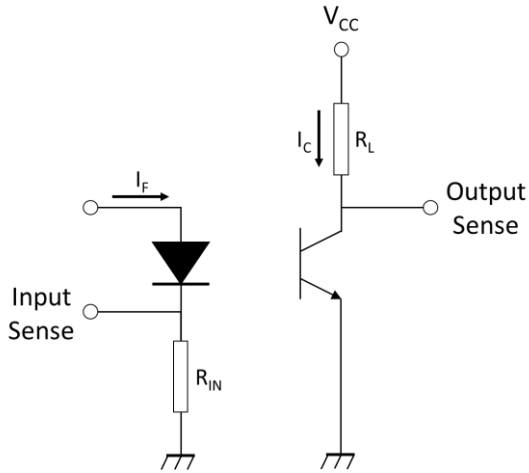


Fig.13 Curves of Response Time

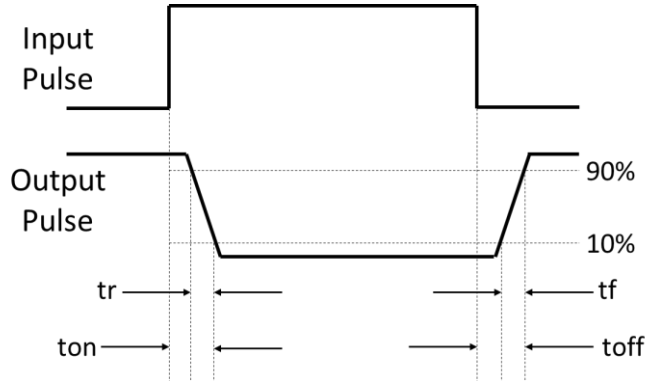
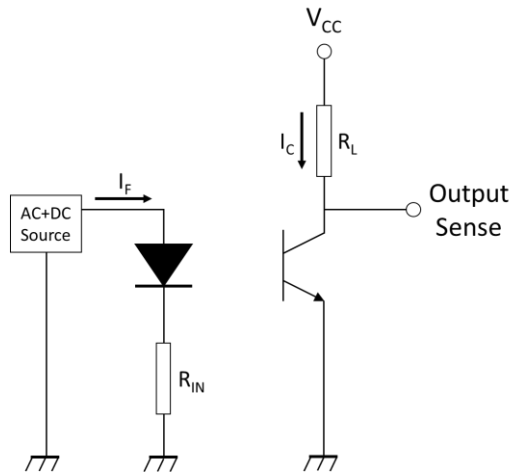


Fig.14 Test Circuits of Frequency Response



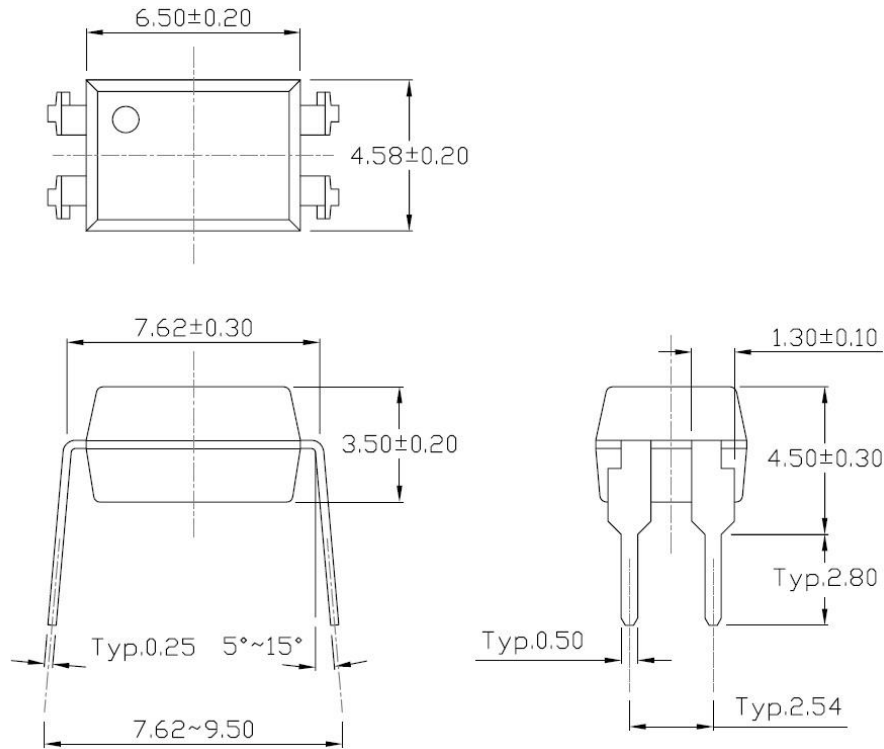


MPC817X1 Series

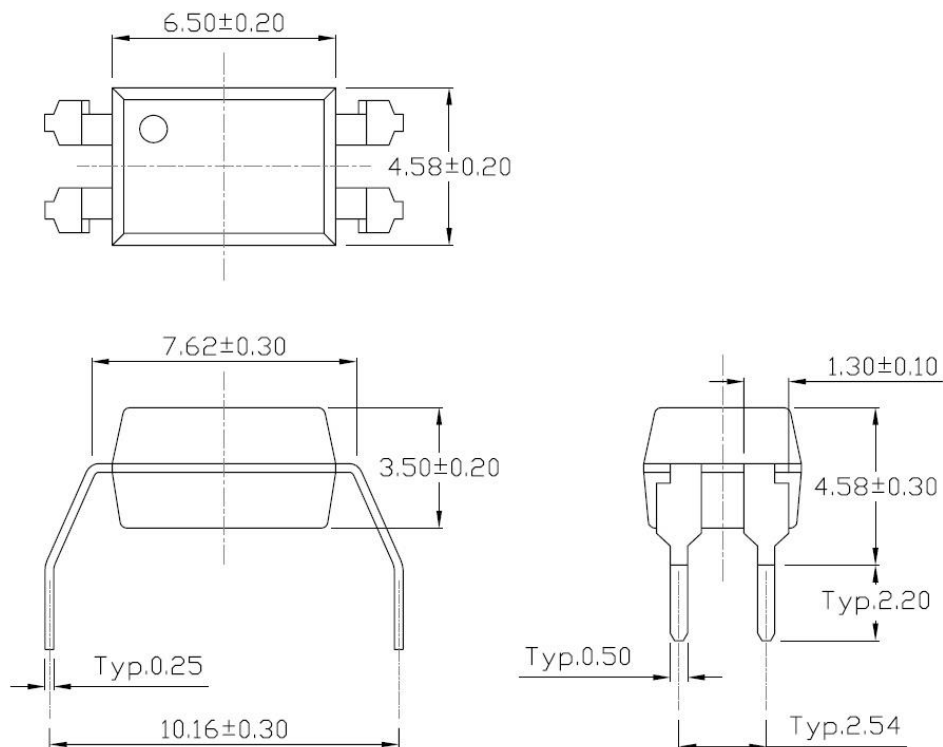
DIP4, DC Input, Photo Transistor Coupler

PACKAGE DIMENSIONS (Dimensions in mm unless otherwise stated)

Standard DIP – Through Hole (DIP Type)



Gullwing (400mil) Lead Forming – Through Hole (M Type)



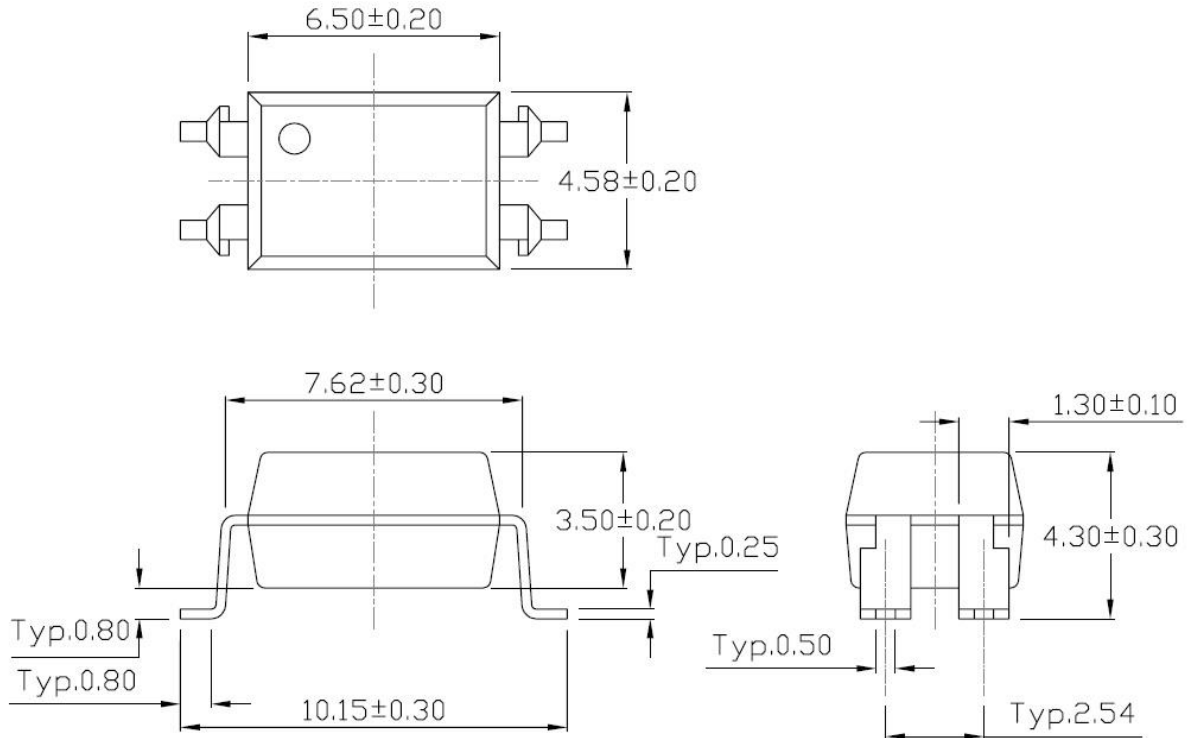


MPC817X1 Series

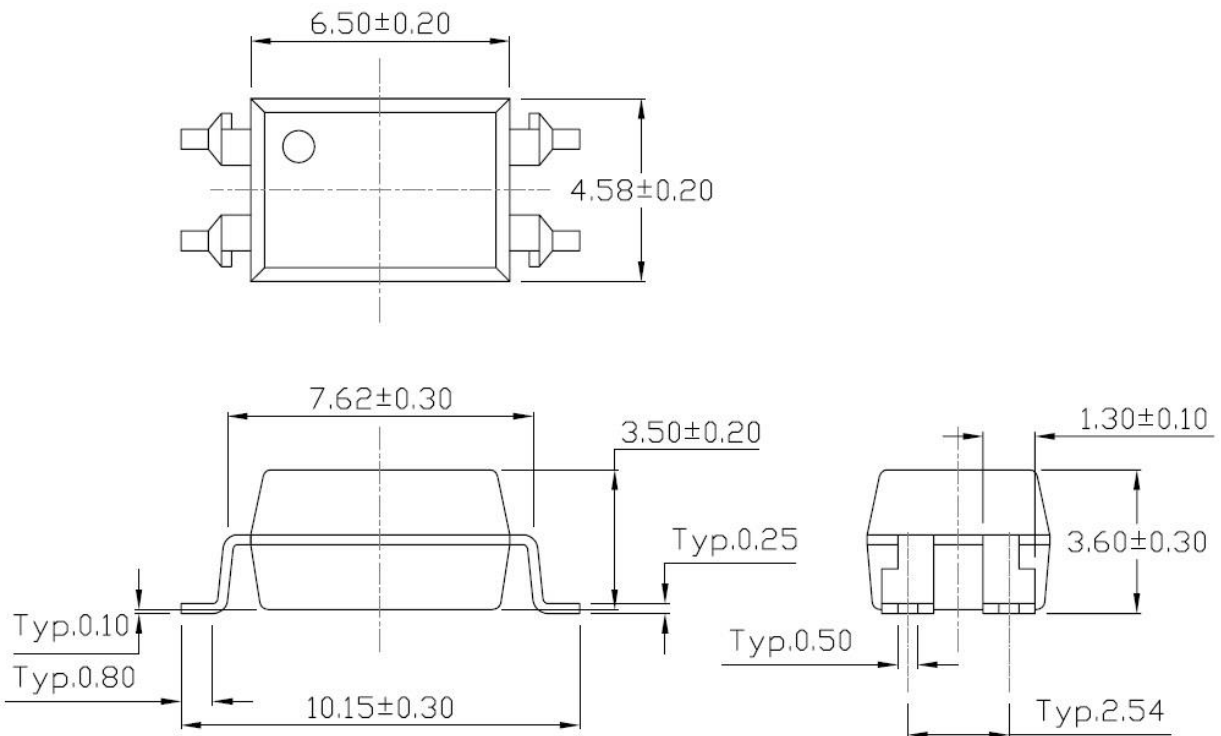
DIP4, DC Input, Photo Transistor Coupler

PACKAGE DIMENSIONS (Dimensions in mm unless otherwise stated)

Surface Mount Lead Forming (S Type)



Surface Mount (Low Profile) Lead Forming (SL Type)



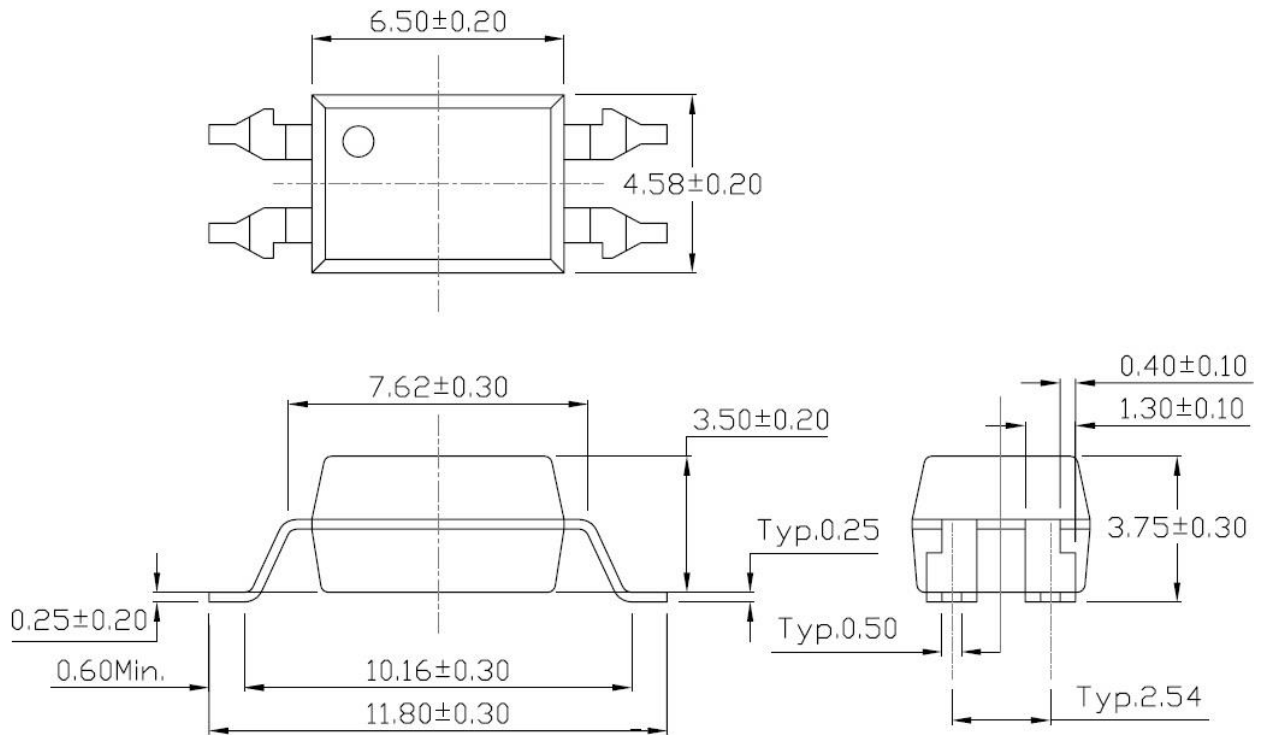


MPC817X1 Series

DIP4, DC Input, Photo Transistor Coupler

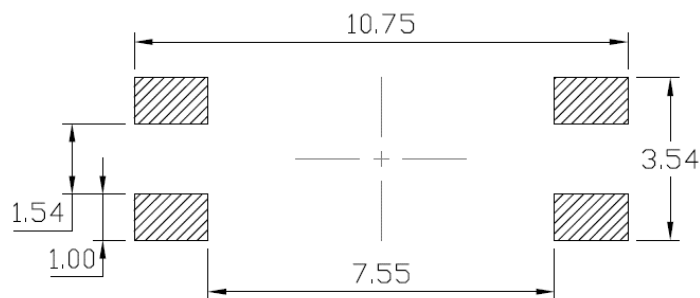
PACKAGE DIMENSIONS (Dimensions in mm unless otherwise stated)

Surface Mount (Gullwing) Lead Forming (SLM Type)

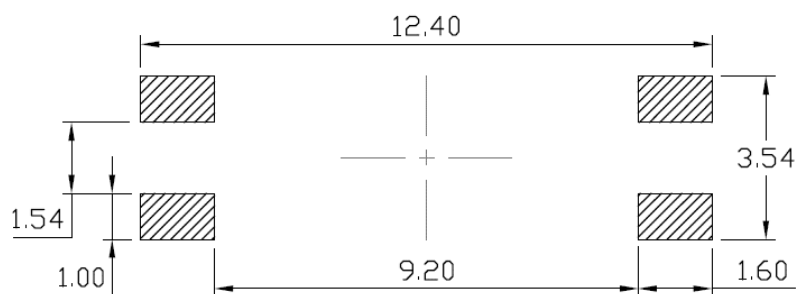


RECOMMENDED SOLDER MASK (Dimensions in mm unless otherwise stated)

Surface Mount Lead Forming & Surface Mount (Low Profile) Lead Forming



Surface Mount (Gullwing) Lead Forming



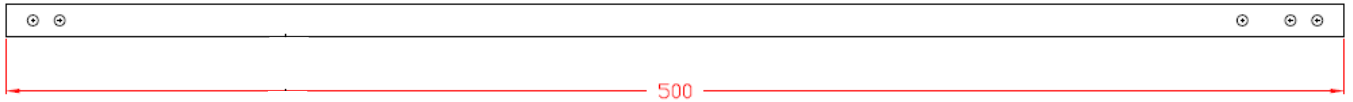
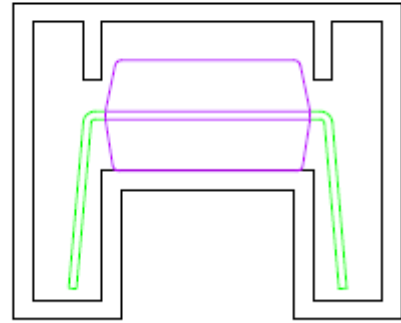
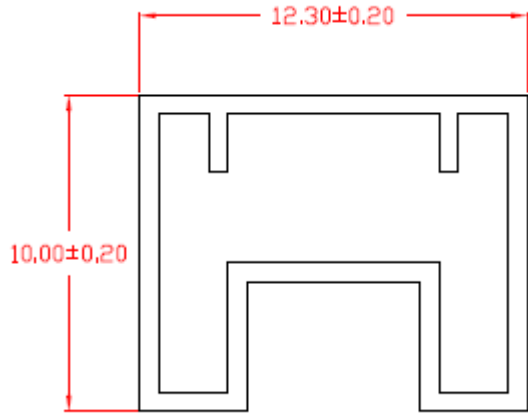


MPC817X1 Series

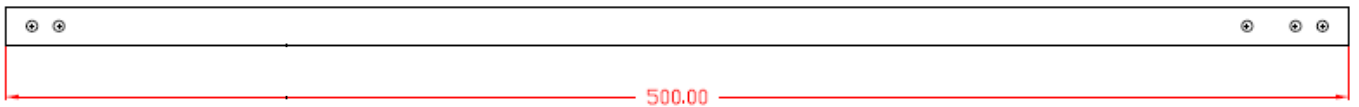
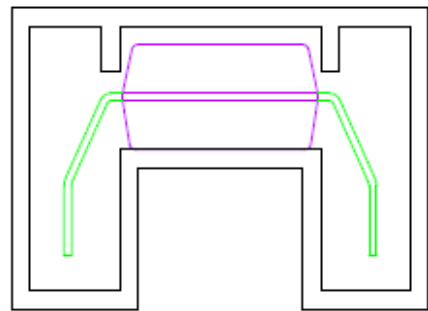
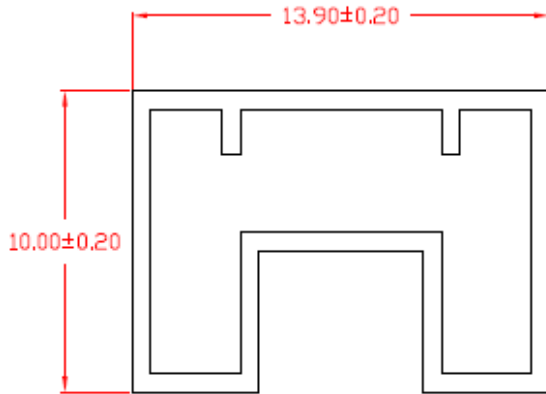
DIP4, DC Input, Photo Transistor Coupler

TUBE SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Standard DIP



Option M



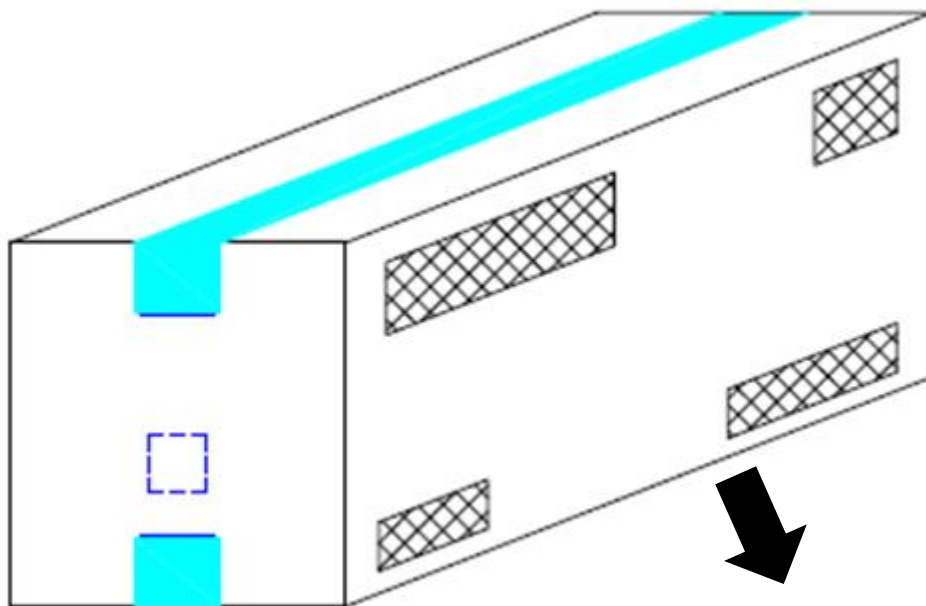
BOX SPECIFICATIONS (Tube Type)

Inner Box



- L x W x H = 52.5cm x 10.7cm x 4.7cm

Outer Box



- L x W x H = 53.5cm x 23.5cm x 25.5cm

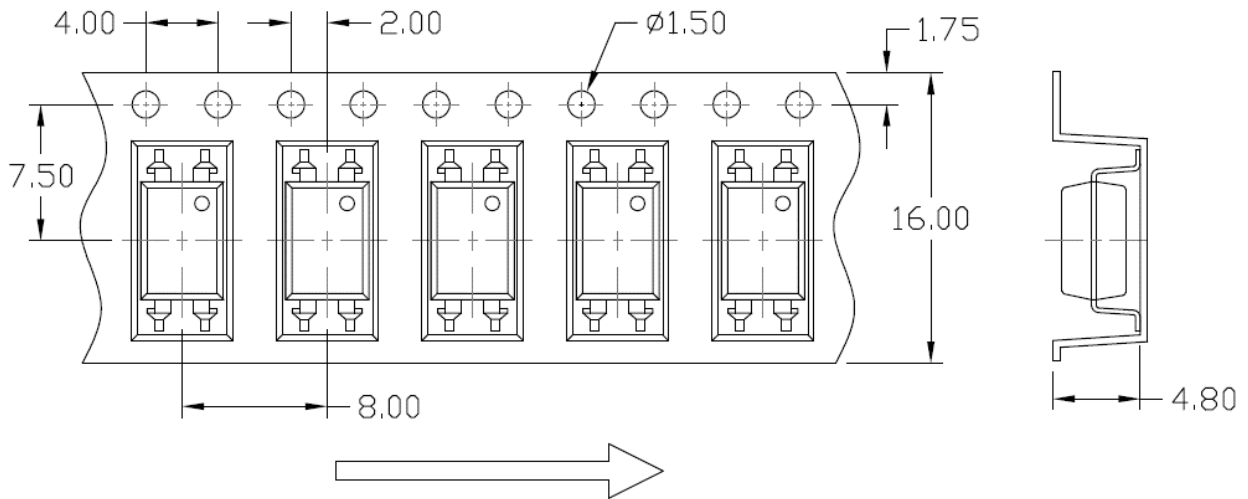


MPC817X1 Series

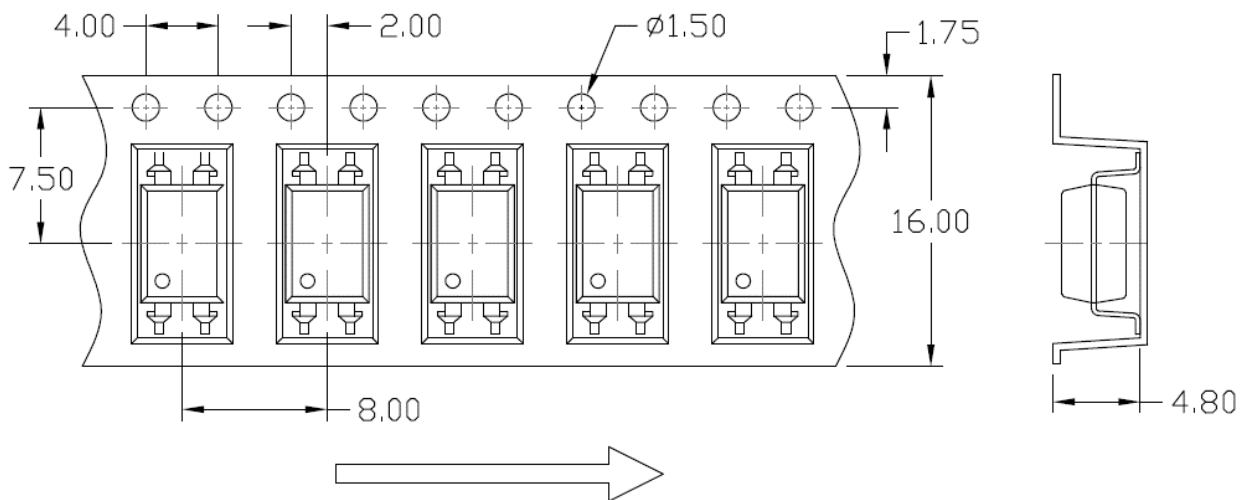
DIP4, DC Input, Photo Transistor Coupler

CARRIER TAPE SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Option S(T1) & SL(T1)



Option S(T2) & SL(T2)



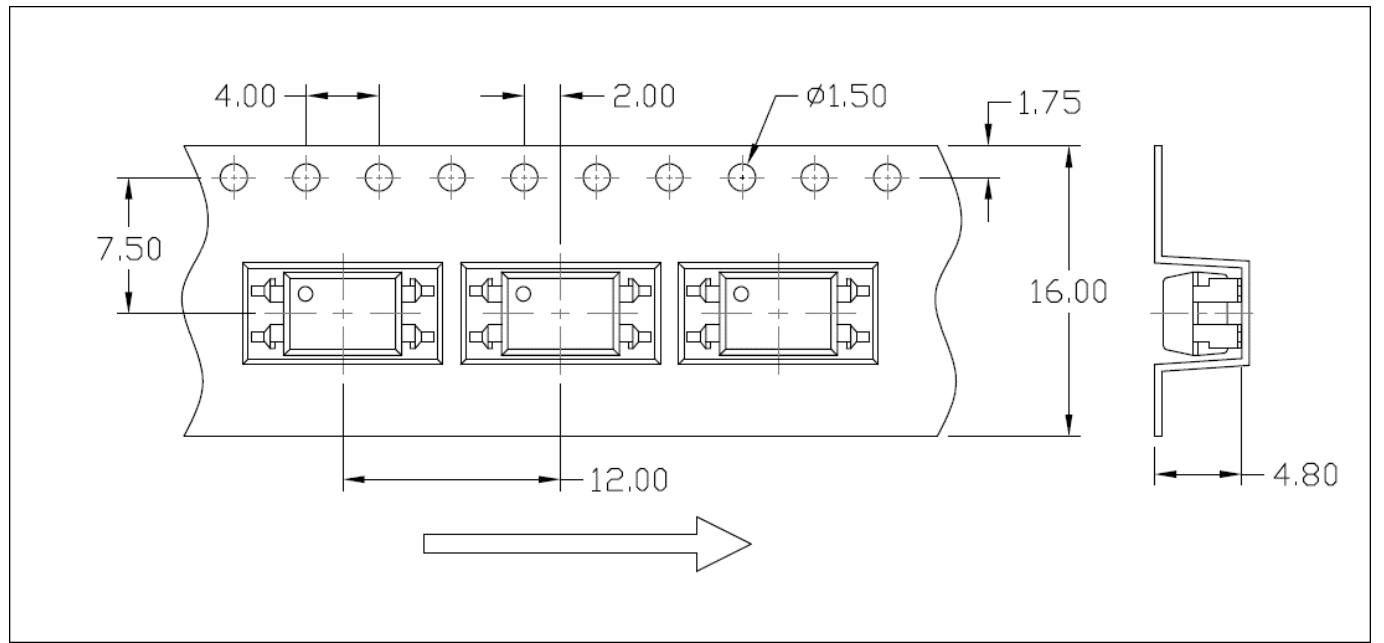


MPC817X1 Series

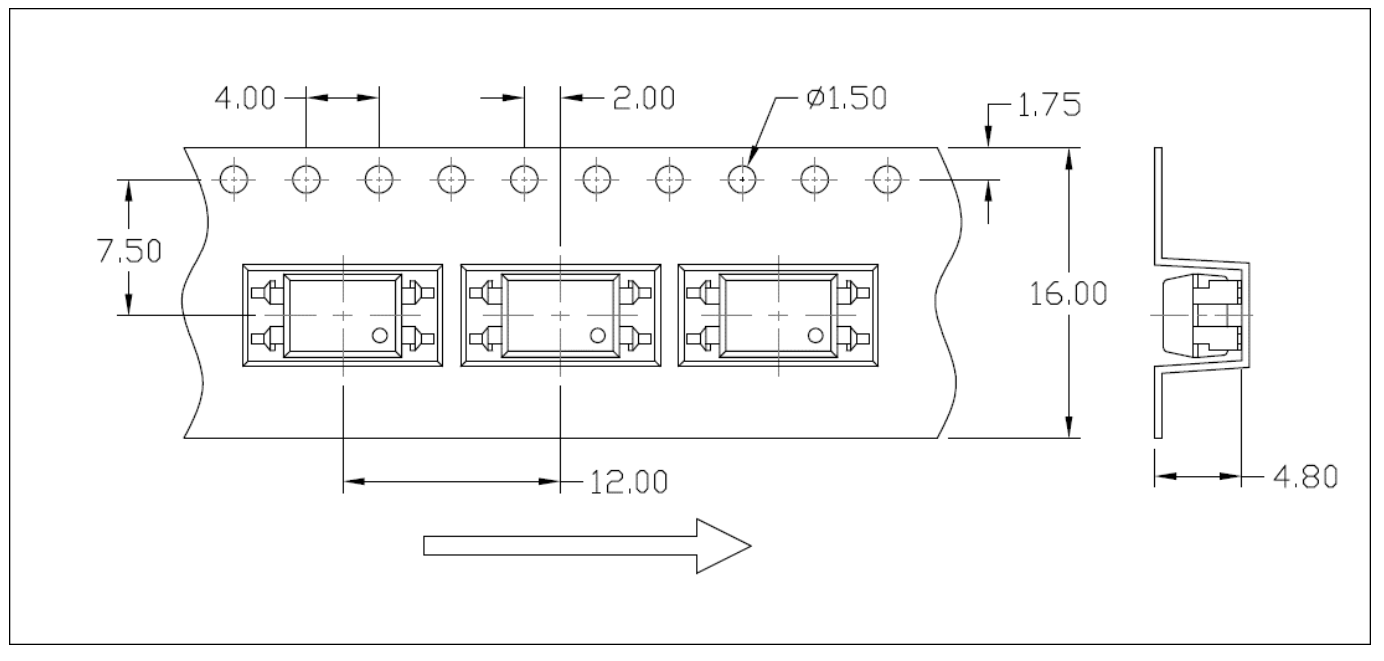
DIP4, DC Input, Photo Transistor Coupler

CARRIER TAPE SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Option S(T3) & SL(T3)



Option S(T4) & SL(T4)



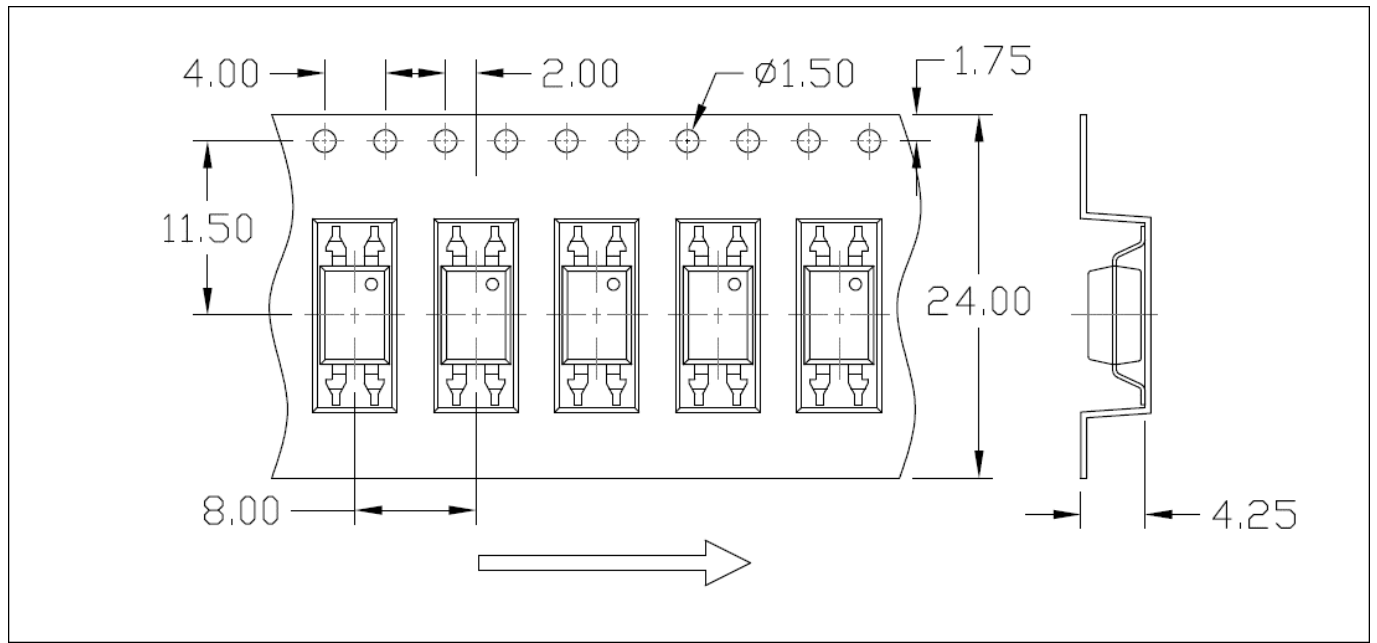


MPC817X1 Series

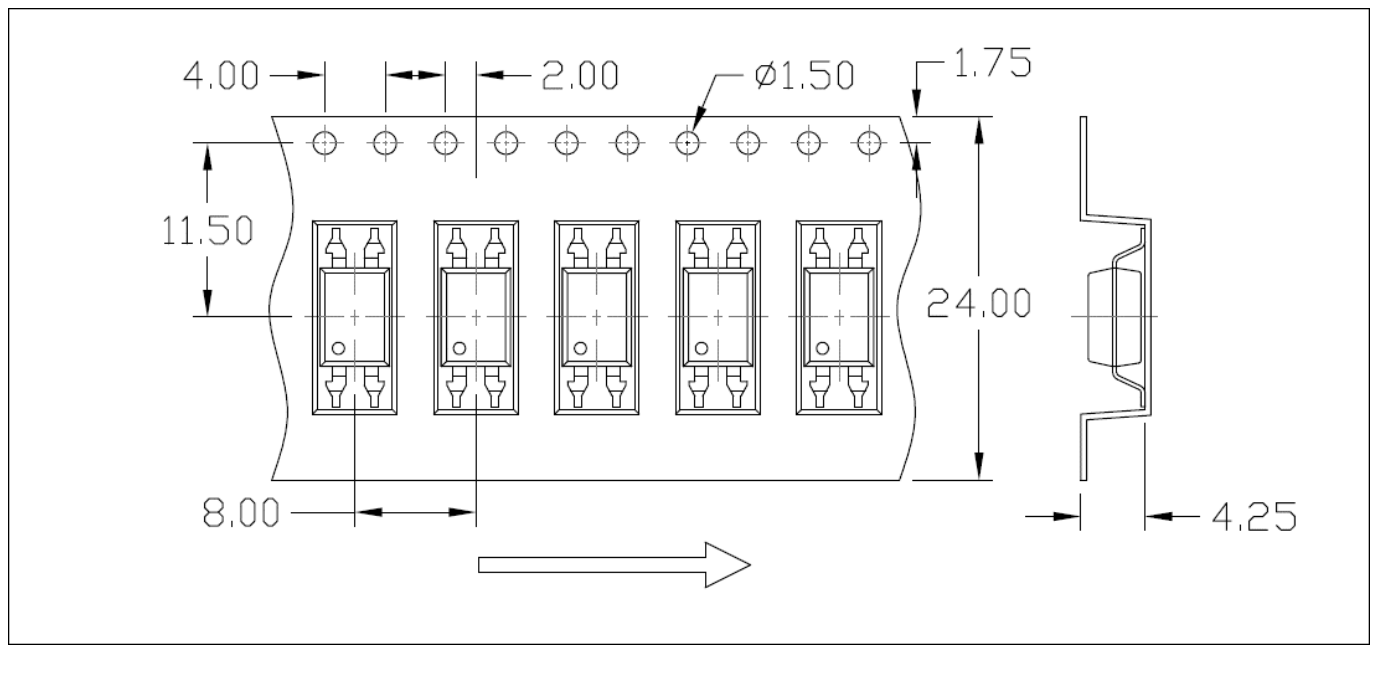
DIP4, DC Input, Photo Transistor Coupler

CARRIER TAPE SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Option SLM(T1)



Option SLM(T2)



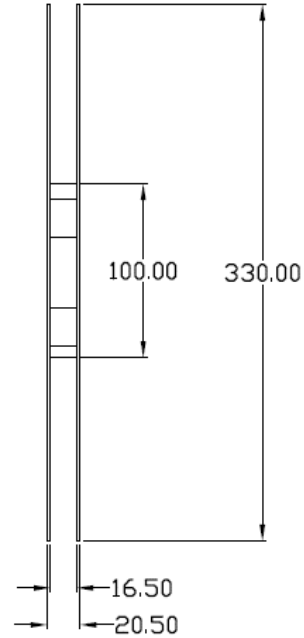
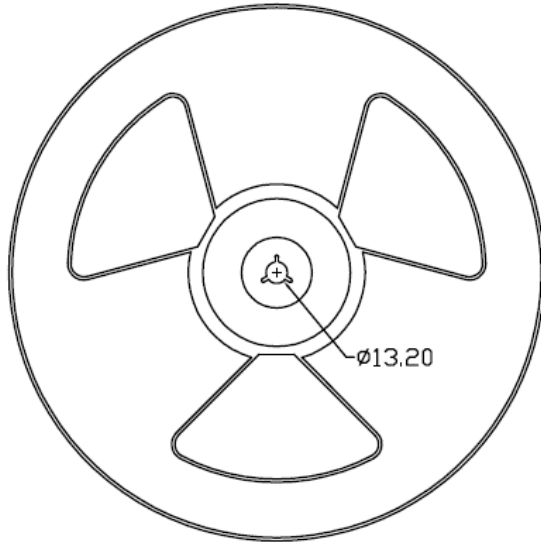


MPC817X1 Series

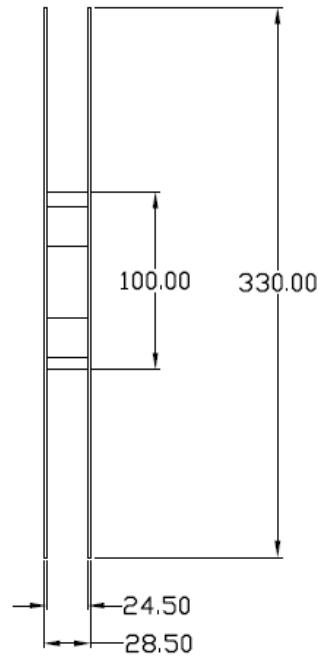
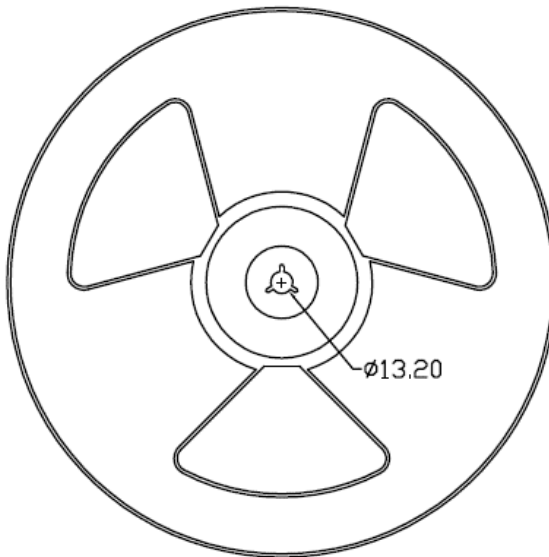
DIP4, DC Input, Photo Transistor Coupler

REEL SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Option S & Option SL

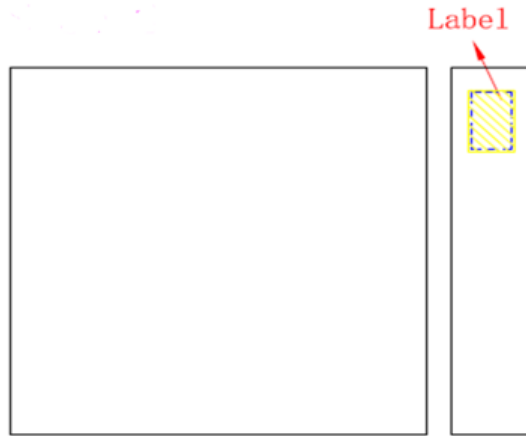


Option SLM



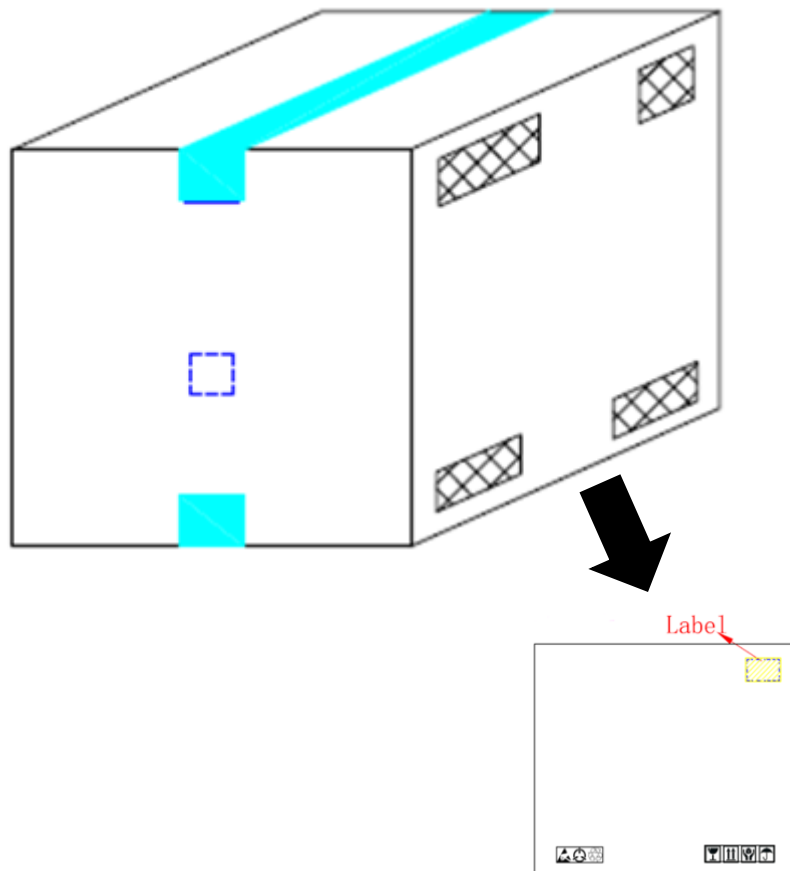
BOX SPECIFICATIONS (Reel Type)

Inner Box



- L x W x H = 36cm x 36cm x 6.9cm

Outer Box



- L x W x H = 45cm x 38cm x 38cm



MPC817X1 Series

DIP4, DC Input, Photo Transistor Coupler

ORDERING AND MARKING INFORMATION

MARKING INFORMATION



MPC : Company Abbr.
817 : Part Number
X : CTR Rank
F : Leadframe Option
V : VDE Option
Y : Fiscal Year
A : Manufacturing Code
WW : Work Week

ORDERING INFORMATION

MPC817X1(Y)(Z)-(F)(G)(V)

MPC – Company Abbr.
 817 – Part Number
 X1 – Rank (A1/B9/C1/D1)
 Y – Lead Form Option (M/S/SL/SLM/None)
 Z – Tape and Reel Option (T1/T2/T3/T4)
 F – Leadframe Option (F:Iron, None:Copper)
 G – Green Option (G or None)
 V – VDE Option (V or None)
 NOTE: It's not applicable to MPC-817B1(Y)(Z)-FGV.

LABEL INFORMATION



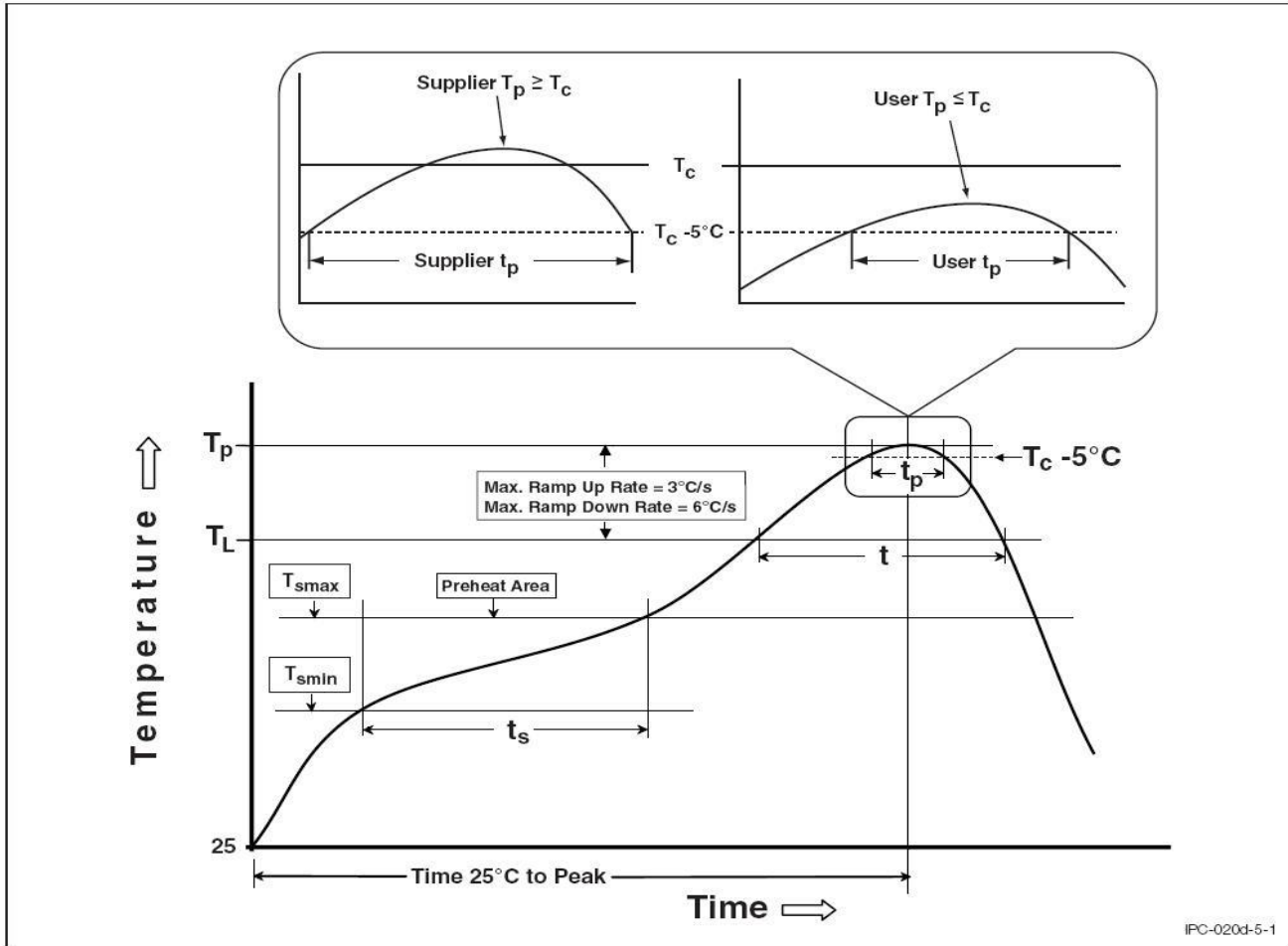
Packing Quantity

Option	Quantity	Quantity – Inner box	Quantity – Outer box
None	100 Units/Tube	32 Tubes/Inner box	10 Inner box/Outer box = 32k Units
M	100 Units/Tube	28 Tubes/Inner box	10 Inner box/Outer box = 32k Units
S(T1)	1500 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 22.5k Units
S(T2)	1500 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 22.5k Units
S(T3)	1000 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 15k Units
S(T4)	1000 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 15k Units
SL(T1)	1500 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 22.5k Units
SL(T2)	1500 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 22.5k Units
SL(T3)	1000 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 15k Units
SL(T4)	1000 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 15k Units
SLM(T1)	1500 Units/Reel	2 Reels/Inner box	5 Inner box/Outer box = 15k Units
SLM(T2)	1500 Units/Reel	2 Reels/Inner box	5 Inner box/Outer box = 15k Units



REFLOW INFORMATION

REFLOW PROFILE



Profile Feature	Sn-Pb Assembly Profile	Pb-Free Assembly Profile
Temperature Min. (T_{smin})	100°C	150°C
Temperature Max. (T_{smax})	150°C	200°C
Time (t_s) from (T_{smin} to T_{smax})	60-120 seconds	60-120 seconds
Ramp-up Rate (t_L to t_P)	$3^\circ\text{C/second max.}$	$3^\circ\text{C/second max.}$
Liquidous Temperature (T_L)	183°C	217°C
Time (t_L) Maintained Above (T_L)	60 – 150 seconds	60 – 150 seconds
Peak Body Package Temperature	$235^\circ\text{C} +0^\circ\text{C} / -5^\circ\text{C}$	$260^\circ\text{C} +0^\circ\text{C} / -5^\circ\text{C}$
Time (t_P) within 5°C of 260°C	20 seconds	30 seconds
Ramp-down Rate (T_P to T_L)	$6^\circ\text{C/second max}$	$6^\circ\text{C/second max}$
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.



MPC817X1 Series

DIP4, DC Input, Photo Transistor Coupler

DISCLAIMER

- MEMCHIP is continually improving the quality, reliability, function and design. MEMCHIP reserves the right to make changes without further notices.
- The characteristic curves shown in this datasheet are representing typical performance which are not guaranteed.
- MEMCHIP makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, MEMCHIP disclaims (a) any and all liability arising out of the application or use of any product, (b) any and all liability, including without limitation special, consequential or incidental damages, and (c) any and all implied warranties, including warranties of fitness for particular
- The products shown in this publication are designed for the general use in electronic applications such as office automation, equipment, communications devices, audio/visual equipment, electrical application and instrumentation purpose, non-infringement and merchantability.
- This product is not intended to be used for military, aircraft, automotive, medical, life sustaining or lifesaving applications or any other application which can result in human injury or death.
- Please contact MEMCHIP sales agent for special application request.
- Immerge unit's body in solder paste is not recommended.
- Parameters provided in datasheets may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated in each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify MEMCHIP's terms and conditions of purchase, including but not limited to the warranty expressed therein.



MPC817X1 Series

DIP4, DC Input, Photo Transistor Coupler

版本 Rev.	生效日期 Effective Date	作者 Applicant	內容 Change Description
1.0	—	—	—
1.1	2021/2/25	Christina Lin	MARKING INFORMATION 正印標示修改:第二行第一個字母“F”移至第三行第一個字母
1.2	2021/4/7	Christina Lin	MPC-817X1 Series 去除字符“-”； ORDERING AND MARKING INFORMATION 中 MPC-817X1(Y)(Z)-FGV 修正為 MPC817X1(Y)(Z)-(F)(G)(V)、Green增加Non-Green之選項、X1 – Rank中B1改為B9
1.3	2022/8/3	Sean Chung	第三頁Current Transfer Ratio中MPC817B1變更成MPC817B9